NX3DV221 High-speed USB 2.0 switch with enable Rev. 4 — 19 June 2013

Product data sheet

1. General description

The NX3DV221 is a high-bandwidth switch designed for the switching of high-speed USB 2.0 signals in handset and consumer applications. These applications could be cell phones, digital cameras, and notebooks with hubs or controllers with limited USB I/Os. The wide bandwidth (1 GHz) of this switch allows signal to pass with minimum edge and phase distortion. The device multiplexes differential outputs from a USB host device to one of two corresponding outputs. The switch is bidirectional and offers little or no attenuation of the high-speed signals at the outputs. It is designed for low bit-to-bit skew and high channel-to-channel noise isolation, and is compatible with various standards, such as high-speed USB 2.0 (480 Mbps).

2. Features and benefits

- Wide supply voltage range from 2.3 V to 3.6 V
- Switch voltage accepts signals up to 5.5 V
- 1.8 V control logic at V_{CC} = 3.6 V
- Low-power mode when OE is HIGH (2 μA maximum)
- 6 Ω (maximum) ON resistance
- 0.1 Ω (typical) ON resistance mismatch between channels
- 6 pF (typical) ON-state capacitance
- High bandwidth (1.0 GHz typical)
- Latch-up performance exceeds 100 mA per JESD 78B Class II Level A
- ESD protection:
 - HBM JESD22-A114F Class 3A exceeds 8000 V
 - CDM JESD22-C101E exceeds 1000 V
 - HBM exceeds 12000 V for I/O to GND protection
- Specified from –40 °C to +85 °C

3. Applications

Routes signals for USB 1.0, 1.1 and 2.0



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4. Ordering information

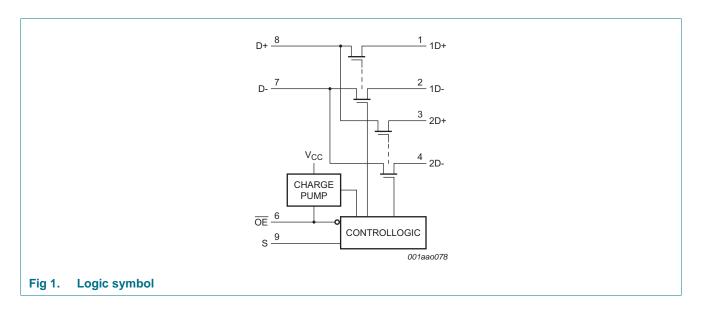
Table 1. Ordering information										
Type number	Package									
	Temperature range	Name	Description	Version						
NX3DV221GM	–40 °C to +85 °C	XQFN10	plastic extremely thin quad flat package; no leads; 10 terminals; body $2 \times 1.55 \times 0.5$ mm	SOT1049-3						
NX3DV221TK	–40 °C to +85 °C	HVSON10	plastic thermal enhanced very thin small outline package; no leads; 10 terminals; $3 \times 3 \times 0.85$ mm	SOT650-2						

5. Marking

Table 2. Marking	
Type number	Marking code ^[1]
NX3DV221GM	x21
NX3DV221TK	x21

[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

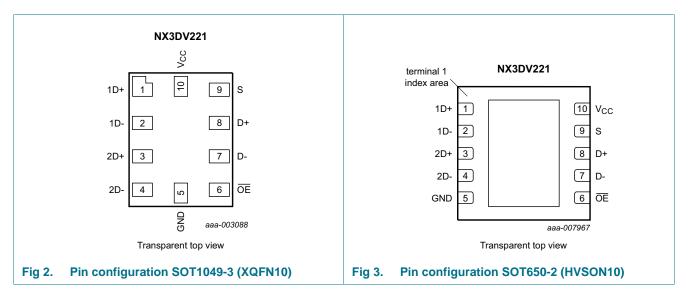
6. Functional diagram



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7. Pinning information

7.1 Pinning



7.2 Pin description

Table 3.	Pin description	
Symbol	Pin	Description
1D+	1	independent input or output
1D-	2	independent input or output
2D+	3	independent input or output
2D-	4	independent input or output
GND	5	ground (0 V)
OE	6	output enable input (active LOW)
D-	7	common input or output
D+	8	common input or output
S	9	select input
V _{CC}	10	supply voltage

8. Functional description

Table 4. Function table^[1]

Input		Channel
S	OE	
L	L	D+ = 1D+; D- = 1D-
Н	L	D+ = 2D+; D- = 2D-
Х	Н	switches off

[1] H = HIGH voltage level; L = LOW voltage level; X = don't care.

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9. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+4.6	V
VI	input voltage	S, OE input	<u>[1]</u> –0.5	+7.0	V
V _{SW}	switch voltage		[2] -0.5	+7.0	V
I _{IK}	input clamping current	V _I < -0.5 V	-50	-	mA
I _{SK}	switch clamping current	V _I < -0.5 V	-50	-	mA
I _{SW}	switch current		-	±120	mA
I _{CC}	supply current		-	+100	mA
I _{GND}	ground current		-100	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	T_{amb} = -40 °C to +125 °C	-	250	mW

[1] The minimum input voltage rating may be exceeded if the input current rating is observed.

[2] The minimum and maximum switch voltage ratings may be exceeded if the switch clamping current rating is observed.

10. Recommended operating conditions

Table 6. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		2.3	3.6	V
VI	input voltage	S, OE input	0	V _{CC}	V
V _{SW}	switch voltage		0	5.5	V
T _{amb}	ambient temperature		-40	+85	°C

11. Static characteristics

Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground 0 V).

Symbol	Parameter	Conditions	Ta	T _{amb} = 25 °C			C to +85 °C	Unit
			Min	Тур	Max	Min	Max	
V _{IH}	HIGH-level	V_{CC} = 2.3 V to 2.7 V	-	-	-	0.46V _{CC}	-	V
inpu	input voltage	V_{CC} = 2.7 V to 3.6 V	-	-	-	$0.46V_{CC}$	-	V
V _{IL} LO	LOW-level input voltage	V_{CC} = 2.3 V to 2.7 V	-	-	-	-	$0.25V_{CC}$	V
		V_{CC} = 2.7 V to 3.6 V	-	-	-	-	$0.25V_{CC}$	V
V _{IK}	input clamping voltage	$V_{CC} = 2.7 \text{ V}, 3.6 \text{ V};$ $I_{I} = -18 \text{ mA}$	-	-	-	-	-1.8	V
I _I	input leakage current	S, \overline{OE} input; V _{CC} = 0 V, 2.7 V, 3.6; V _I = GND to 3.6 V	-	0.01	-	-	±1	μΑ

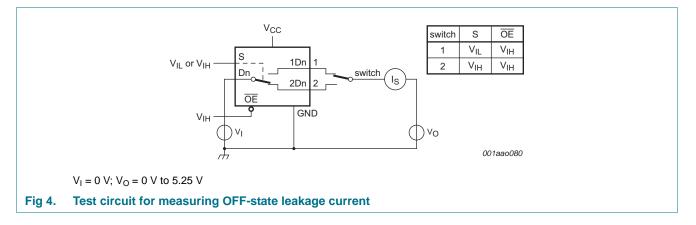
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Parameter Conditions T_{amb} = 25 °C T_{amb} =-40 °C to +85 °C Symbol Unit Min Max Min Max Тур per pin; $V_{CC} = 0 V$ power-off IOFF leakage current $V_{SW} = 0 V \text{ to } 2.7 V$ 0.01 ±2.0 μΑ _ _ _ $V_{SW} = 0 V$ to 3.6 V 0.01 ±2.0 μΑ --- $V_{SW} = 0 V \text{ to } 5.25 V$ 0.01 ±3.0 _ -μΑ **OFF-state** nD+ and nD- ports; I_{S(OFF)} leakage current see Figure 4 $V_{CC} = 2.7 \text{ V}, 3.6 \text{ V}$ ±1 μΑ --_ -V_{CC} = 2.7 V, 3.6 V supply current I_{CC} $\overline{OE} = GND$ 18.5 30 μΑ _ _ _ $\overline{OE} = V_{CC}$ (low-power 0.01 2 μΑ -mode) S, OE input; additional ΔI_{CC} one input at 1.8 V: supply current other inputs at GND or V_{CC} $V_{CC} = 2.7 V$ 0.8 1.8 μΑ --- $V_{CC} = 3.6 V$ 12.5 -20 μΑ -- $V_{SW} = GND \text{ or } V_{CC};$ Cı 1 2.5 pF input _ _ _ V_{CC} = 2.5 V, 3.3 V capacitance $V_{SW} = GND \text{ or } V_{CC};$ **OFF-state** 3 5.0 pF C_{S(OFF)} _ --V_{CC} = 2.5 V, 3.3 V capacitance **ON-state** $V_{SW} = GND \text{ or } V_{CC};$ 6 7.5 pF $C_{S(ON)}$ _ _ _ V_{CC} = 2.5 V, 3.3 V capacitance

Static characteristics ... continued Table 7.

At recommended operating conditions; voltages are referenced to GND (ground 0 V).

Test circuits 11.1



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11.2 ON resistance

Table 8.ON resistance

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for graphs see Figure 6.

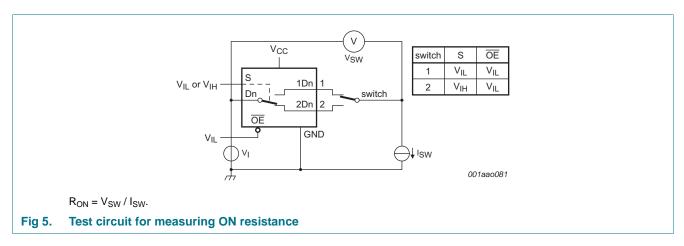
Symbol	Parameter	Conditions	s $T_{amb} = -40 \text{ °C to } +85 \text{ °C}$		+85 °C	T _{amb} =40 °	°C to +85 °C	Unit	
				Min	Typ <mark>[1]</mark>	Max	Min	Max	
R _{ON}	ON resistance	V _{CC} = 2.3 V, 3.0 V see <u>Figure 5</u>							
		$V_{I} = 0 V;$ $I_{I} = 30 mA$		-	3.6	-	-	6	Ω
		$V_{I} = 2.4 V;$ $I_{I} = -15 mA$		-	4.3	-	-	7	Ω
ΔR_{ON}	ON resistance	V_{CC} = 2.3 V, 3.0 V	[2]						
	mismatch between channels	$V_{I} = 0 V;$ $I_{I} = 30 mA$		-	0.1	-	-	-	Ω
		$V_{I} = 1.7 V;$ $I_{I} = -15 mA$		-	0.1	-	-	-	Ω
R _{ON(flat)}	ON resistance (flatness)	$V_{CC} = 2.3 \text{ V}, 3.0 \text{ V};$ $V_{I} = 0 \text{ V to } V_{CC}$	[3]						
		I _I = 30 mA		-	0.8	-	-	-	Ω
		I _I = -15 mA		-	0.7	-	-	-	Ω

[1] Typical values are measured at $T_{amb} = 25 \text{ °C}$.

[2] Measured at identical V_{CC} , temperature and input voltage.

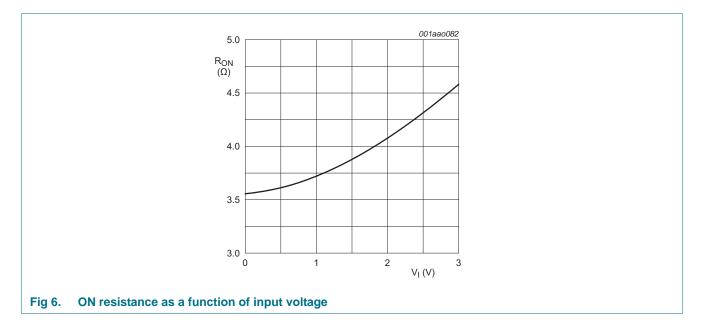
[3] Flatness is defined as the difference between the maximum and minimum value of ON resistance measured at identical V_{CC} and temperature.

11.3 ON resistance test circuit and waveforms



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12. Dynamic characteristics

Table 9. Dynamic characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for test circuit, see Figure 10.

Symbol	Parameter	Conditions		Ta	_{mb} = 25	°C	$T_{amb} = -40$	°C to +85 °C	Unit
				Min	Typ <mark>[1]</mark>	Max	Min	Max	
t _{pd}	propagation delay	Dn to nDn or nDn to Dn; see <u>Figure 7</u>	<u>[2][3]</u>					'	•
		V_{CC} = 2.3 V to 2.7 V		-	0.25	-	-	-	ns
		V_{CC} = 3.0 V to 3.6 V		-	0.25	-	-	-	ns
t _{en}	enable time	S to Dn, nDn; see <mark>Figure 9</mark>	<u>[3]</u>						
		V_{CC} = 2.3 V to 2.7 V		-	-	-	-	50	ns
		V_{CC} = 3.0 V to 3.6 V		-	-	-	-	30	ns
		OE to Dn, nDn; see <u>Figure 9</u>	<u>[3]</u>						
		V_{CC} = 2.3 V to 2.7 V		-	-	-	-	32	ns
		V_{CC} = 3.0 V to 3.6 V		-	-	-	-	17	ns
t _{dis}	disable time	S to Dn, nDn; see <u>Figure 9</u>	<u>[3]</u>						
		V_{CC} = 2.3 V to 2.7 V		-	-	-	-	23	ns
		V_{CC} = 3.0 V to 3.6 V		-	-	-	-	12	ns
		OE to Dn, nDn; see <u>Figure 9</u>	<u>[3]</u>						
		V_{CC} = 2.3 V to 2.7 V		-	-	-	-	12	ns
		V_{CC} = 3.0 V to 3.6 V		-	-	-	-	10	ns

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Symbol	Parameter	Conditions		T _{amb} = 25 °C			T _{amb} = -40 °	°C to +85 °C	Unit
				Min	Typ[1]	Max	Min	Max	
t _{sk(o)} output skew time	output skew time	see Figure 8	[4]						
		V_{CC} = 2.3 V to 2.7 V		-	0.1	-	-	0.2	ns
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		-	0.1	-	-	0.2	ns
t _{sk(p)}	pulse skew time	see Figure 7	[4]						
		V_{CC} = 2.3 V to 2.7 V		-	0.1	-	-	0.2	ns
		V_{CC} = 3.0 V to 3.6 V		-	0.1	-	-	0.2	ns

Table 9. Dynamic characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for test circuit, see Figure 10.

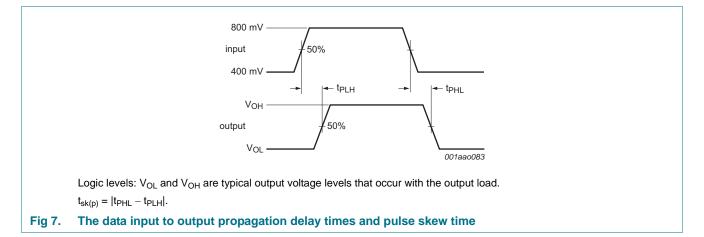
[1] Typical values are measured at $T_{amb} = 25 \text{ °C}$ and $V_{CC} = 2.5 \text{ V}$ and 3.3 V respectively.

[2] The propagation delay is the calculated RC time constant of the typical ON resistance of the switch and the specified load capacitance, when driven by an ideal voltage source (zero output impedance).

[3] t_{pd} is the same as t_{PLH} and t_{PHL} .

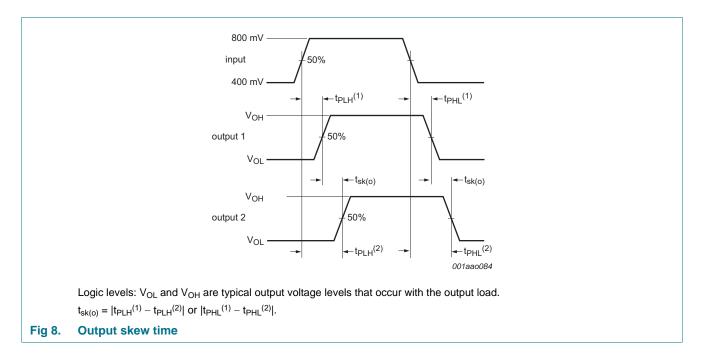
[4] Guaranteed by design.

12.1 Waveforms, test circuit and graphs



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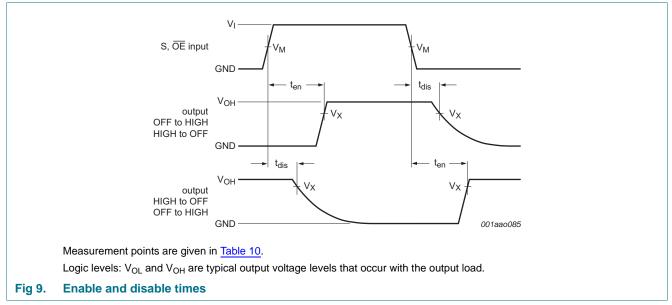


Table 10. Measurement points

Supply voltage	Input	Output	
V _{CC}	V _M	VI	V _X
2.3 V to 3.6 V	0.5V ₁	1. 8 V	0.9V _{OH}

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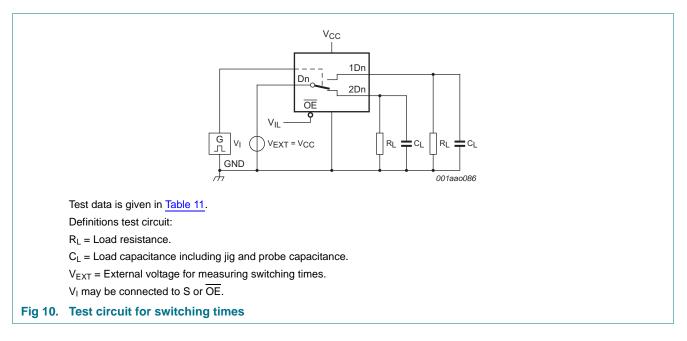
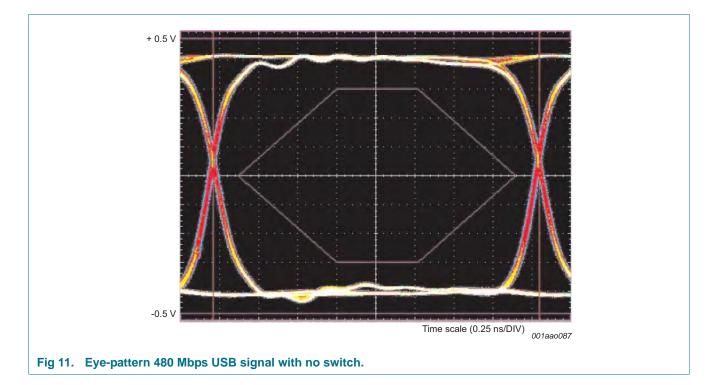
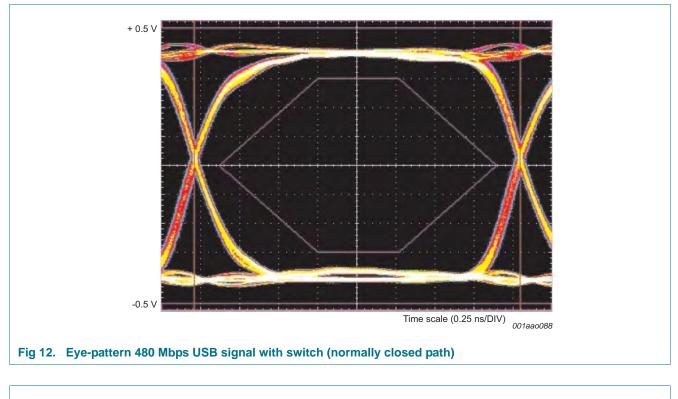


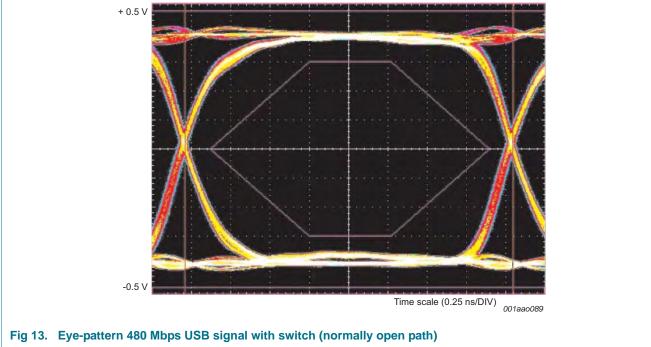
Table 11. Test data

Supply voltage	Input		Load		
V _{cc}	VI	t _r , t _f	C∟	RL	
2.3 V to 3.6 V	1.8 V	≤ 5 ns	50 pF	500 Ω	



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12.2 Additional dynamic characteristics

Table 12. Additional dynamic characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); $V_I = GND$ or V_{CC} (unless otherwise specified); $t_r = t_f \le 5$ ns; $T_{amb} = 25$ °C.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
f _(-3dB)	–3 dB frequency response	$R_L = 50 \Omega$; see Figure 14	[1][2]				
		V_{CC} = 2.3 V to 2.7 V		-	1.0	-	GHz
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		-	1.0	-	GHz
α_{iso}	isolation (OFF-state)	$f_i = 250 \text{ MHz}; \text{ R}_L = 50 \Omega; \text{ see } \frac{\text{Figure 15}}{1000}$	[1][2]				
		V_{CC} = 2.3 V to 2.7 V		-	-38	-	dB
		V_{CC} = 3.0 V to 3.6 V		-	-38	-	dB
Xtalk	crosstalk	between switches; $f_i = 250 \text{ MHz; } R_L = 50 \Omega$; see Figure 16	<u>[1][2]</u>				
		V_{CC} = 2.3 V to 2.7 V		-	-40	-	dB
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		-	-40	-	dB

[1] f_i is biased at 350 mV.

[2] V_i = 632 mV (p-p).

12.3 Test circuits

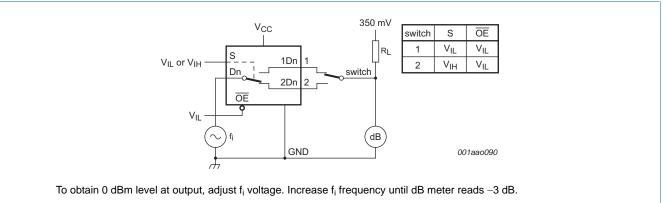


Fig 14. Test circuit for measuring the frequency response when switch is in ON-state

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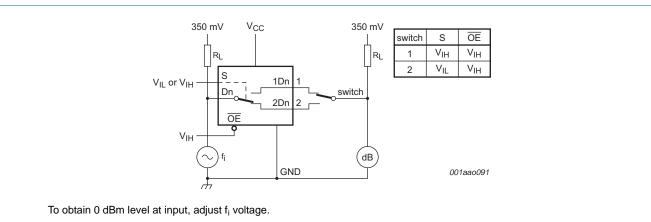
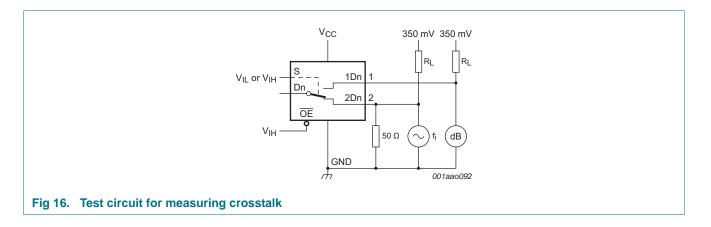


Fig 15. Test circuit for measuring isolation (OFF-state)

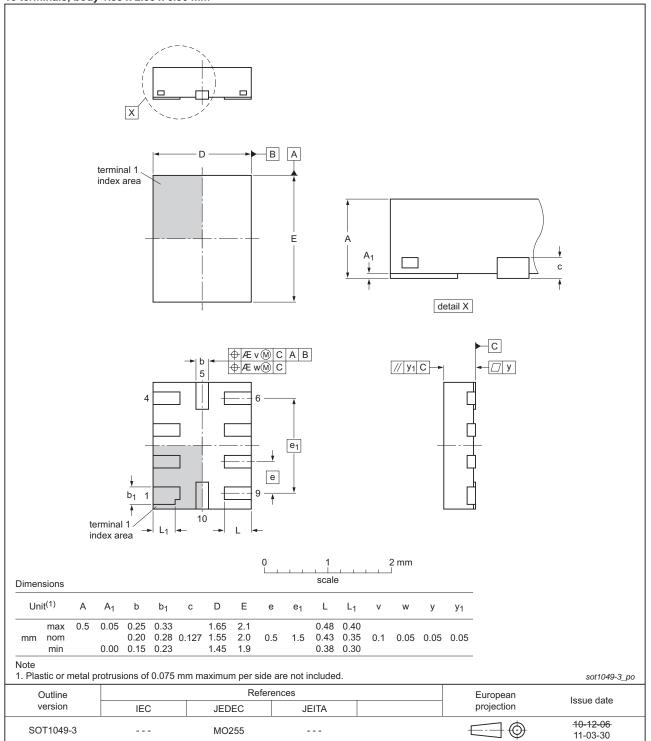


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SOT1049-3

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13. Package outline

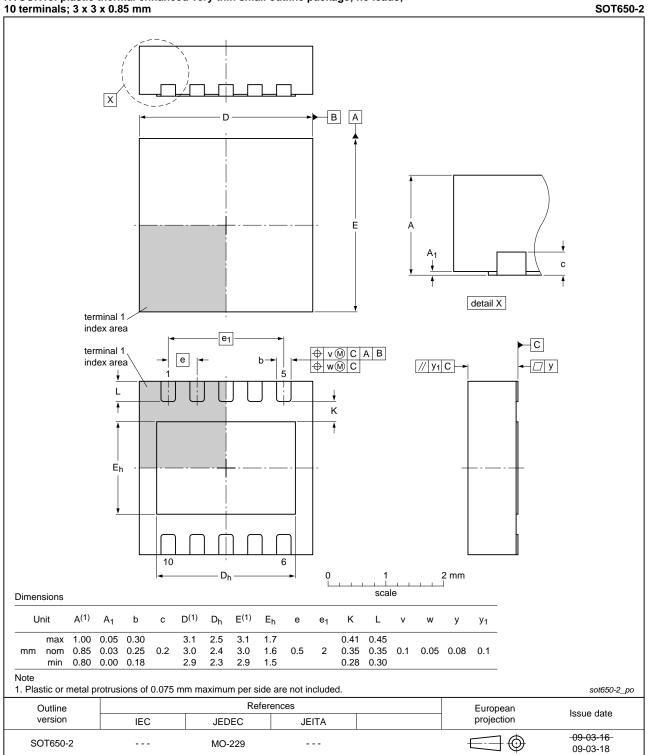


XQFN10: plastic, extremely thin quad flat package; no leads; 10 terminals; body 1.55 x 2.00 x 0.50 mm

Fig 17. Package outline SOT1049-3 (XQFN10)

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HVSON10: plastic thermal enhanced very thin small outline package; no leads; 10 terminals; 3 x 3 x 0.85 mm

Fig 18. Package outline SOT650-2 (HVSON10)

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14. Abbreviations

Table 13. Abbreviations		
Acronym	Description	
CDM	Charged Device Model	
CMOS	Complementary Metal Oxide Semiconductor	
ESD	ElectroStatic Discharge	
HBM	Human Body Model	
MM	Machine Model	

15. Revision history

Table 14. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
NX3DV221 v.4	20130619	Product data sheet	-	NX3DV221 v.3
Modifications:	 Type number 	er NX3DV221TK added.		
	 Package ou 	Itline drawing added (Figure	<u>e 18</u>).	
NX3DV221 v.3	20120705	Product data sheet	-	NX3DV221 v.2
NX3DV221 v.2	20111109	Product data sheet	-	NX3DV221 v.1
NX3DV221 v.1	20110421	Product data sheet	-	-

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16.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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[2] The term 'short data sheet' is explained in section "Definitions".

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High-speed USB 2.0 switch with enable

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